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View Online at https://aerobasegroup.com/nsn/5961-01-168-3349

Inclosure Material: Metal **Overall Length:** 0.820 inches **Overall Height:** 0.455 inches **Overall Width:** 0.250 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 regulator voltage **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 40.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius ambient air **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No

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